

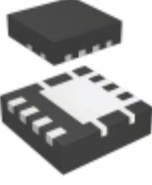



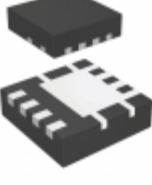


	<h2 style="color: red;">FDMC8200S</h2>
	<p>Hersteller-Teilenummer: FDMC8200S</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET 2N-CH 30V 6A/8.5A 8MLP</p> <hr/> <p>Datenblätter:  FDMC8200S.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 39711 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMC8200S
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 30V 6A/8.5A 8MLP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	39711 pcs Stock
Hersteller Standard Vorlaufzeit	18 Weeks
detaillierte Beschreibung	Mosfet Array 2 N-Channel (Dual) 30V 6A, 8.5A 700mW,
Serie	PowerTrench®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	700mW, 1W
Verpackung / Gehäuse	8-PowerWDFN
Supplier Device-Gehäuse	8-Power33 (3x3)
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A, 8.5A
Rds On (Max) @ Id, Vgs	20 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	10nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	660pF @ 15V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FDMC8200SCT



















































FDMC8200S ist neu im Original, Suche FDMC8200S Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMC8200S AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FDMC8200S: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDMC8298 Fairchild Fairchild POWER33</p>	 <p>FDMC8296 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 12A POWER33</p>	 <p>FDMC8097AC Fairchild/ON Semiconductor MOSFET N/P-CH 150V</p>	 <p>FDMC8097AC AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 150V</p>
 <p>FDMC8200 AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 8A/12A POWER33</p>	 <p>FDMC8296 Fairchild/ON Semiconductor MOSFET N-CH 30V 12A POWER33</p>	 <p>FDMC8200S_F106 AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 6A/8.5A 8MLP</p>	 <p>FDMC8296. FAI FDMC8296. FAI</p>

heiße Teile

Mehr

 FDMC7660S	 FDMC7664	 FDMC7664	 FDMC7672	 FDMC7672
 FDMC7672S	 FDMC7672S	 FDMC7678	 FDMC7678	 FDMC7680
 FDMC7680	 FDMC7692	 FDMC7692	 FDMC7692S	 FDMC7692S
 FDMC7696	 FDMC7696	 FDMC8010	 FDMC8010	 FDMC8015L
 FDMC8015L	 FDMC8026S	 FDMC8026S	 FDMC8200	 FDMC8200
 FDMC8200S	 FDMC8296	 FDMC8296	 FDMC8296.	 FDMC8298
 FDMC8298	 FDMC8321L	 FDMC8321L	 FDMC8327L	 FDMC8327L
 FDMC8462	 FDMC8462	 FDMC8554	 FDMC8554	 FDMC8588
 FDMC8588	 FDMC8588A	 FDMC8588DC	 FDMC8588DC	 FDMC86012
 FDMC86012	 FDMC86102	 FDMC86102	 FDMC86102LZ	 FDMC86102LZ

Contact us: Info@Y-IC.com

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